Nch 100V 300A Wide-SOA Power MOSFET

V _{DSS}	100V
R _{DS(on)} (Max.)	1.86mΩ
I _D	±300A
P_D	340W

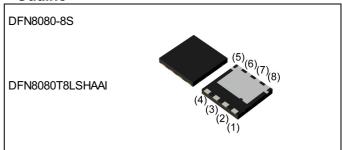
Features

- 1) Low on resistance
- 2) High power package (DFN8080)
- 3) Pb-free plating; RoHS compliant
- 4) Halogen Free
- 5) 100% Rg and UIS tested
- 6) Wide-SOA

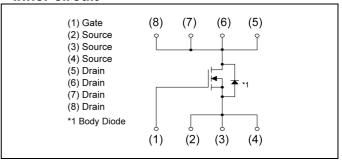
Application

Hot Swap Controller(HSC)

Outline



•Inner circuit



Packaging specifications

	Jing opcomoducino	
	Packing	Embossed Tape
	Reel size (mm)	330
Туре	Tape width (mm)	16
	Quantity (pcs)	2500
	Taping code	TBC
	Marking	RY7P250BM

● **Absolute maximum ratings** (T_a = 25°C ,unless otherwise specified)

Para	meter	Symbol	Value	Unit
Drain - Source voltage	V_{DSS}	100	V	
Continuous drain surrent	Silicon limit (V _{GS} =10V)	I _D *1	±300	Α
Continuous drain current	$T_c = 25^{\circ}C (V_{GS} = 10V)$	I _D *2	±250	Α
Pulsed drain current		I _{DP} *3	±900	Α
Gate - Source voltage		V_{GSS}	±20	V
Avalanche current, single pulse		I _{AS} *4	79	Α
Avalanche energy, single pulse		E _{AS} *4	497	mJ
Power dissipation		P _D *2	340	W
Junction temperature		T _j	175	°C
Operating junction and storage temperature range		T _{stg}	-55 to +175	°C

●Thermal resistance

Doromotor	Cymab al	Values			l limit
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	R _{thJC} *2	-	-	0.44	°C/W
Thermal resistance, junction - ambient	R _{thJA} *5	-	35	-	°C/W

● Electrical characteristics (T_a = 25°C)

Davamatav	Cymah al	Canditions	Values			l limit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Drain - Source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D = 1mA	100	-	-	V
Breakdown voltage temperature coefficient	$\frac{\Delta V_{(BR)DSS}}{\Delta T_{j}}$	$\frac{\Delta V_{(BR)DSS}}{\Delta T_i} I_D = 1 \text{mA}$ referenced to 25°C		58.4	-	mV/°C
Zero gate voltage drain current	I _{DSS}	V _{DS} = 100V, V _{GS} = 0V	-	-	5	μA
Gate - Source leakage current	I _{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	-	±500	nA
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = 1mA$	2.0	-	4.0	V
Gate threshold voltage temperature coefficient	$\frac{\DeltaV_{GS(th)}}{\DeltaT_j}$	I _D = 1mA referenced to 25°C	-	-5.6	-	mV/°C
Static drain - source on - state resistance	R _{DS(on)} *6	V _{GS} = 10V, I _D = 50A	-	1.43	1.86	mΩ
Gate resistance	R_{G}	-	0.9	1.9	3.8	Ω
Forward Transfer Admittance	Y _{fs} *6	V _{DS} = 5V, I _D = 50A	27	-	-	S

^{*1} Limited by silicon chip capability.



^{*2} T_c =25°C, Limited only by maximum temperature allowed.

^{*3} Pw \leq 10µs, Duty cycle \leq 1%

^{*4} L \simeq 0.1mH, V_{DD} = 50V, R_G = 25 Ω , Starting T_j = 25 $^{\circ}$ C Fig.3-1,3-2

^{*5} Mounted on Cu board (25.4mm×25.4mm×70um)

^{*6} Pulsed

● Electrical characteristics (T_a = 25°C)

Darameter	Cumbal	Conditions		Unit		
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input capacitance	C _{iss}	V _{GS} = 0V	*6780	11300	*15900	
Output capacitance	C _{oss}	V _{DS} = 50V	*1060	1760	*2470	pF
Reverse transfer capacitance	C _{rss}	f = 1MHz	*28	55	*110	
Turn - on delay time	t _{d(on)} *6	$V_{DD} \simeq 50V, V_{GS} = 10V$	-	72	-	
Rise time	t _r *6	I _D = 50A	-	90	-	no
Turn - off delay time	t _{d(off)} *6	R _L ≃ 1Ω	-	195	-	ns
Fall time	t _f *6	$R_G = 10\Omega$	-	200	-	

^{*:} Guarantee of Design

● Gate charge characteristics (T_a = 25°C)

Parameter	Symbol Conditions			Unit		
- Farameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Total gate charge	Q_g^{*6}	V _{DD} ≈ 50V,	*105	170	*240	
Gate - Source charge	Q _{gs} *6	I _D = 50A,	*32	53	*75	nC
Gate - Drain charge	Q _{gd} *6	V _{GS} = 10V	*15	29	*58	

^{*:} Guarantee of Design

● Body diode electrical characteristics (Source-Drain) (T_a = 25°C)

Parameter	Symbol	ol Conditions		Values			
	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Continuous forward current	I _S *2		1	-	250	Α	
Pulse forward current	I _{SP} *3	-	ı	-	900	Α	
Forward voltage	V _{SD} *6	$V_{GS} = 0V, I_{S} = 50A$	-	-	1.2	V	
Reverse recovery time	t _{rr} *6	I _S = 50A, V _{GS} =0V	-	99	-	ns	
Reverse recovery charge	Q _{rr} *6	di/dt = 100A/µs	-	295	-	nC	

• Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve

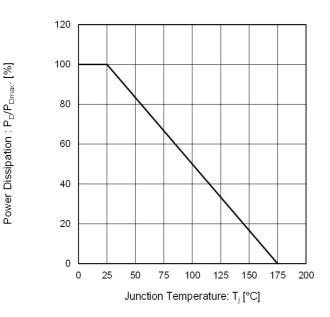
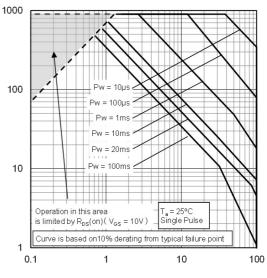


Fig.2 Maximum Safe Operating Area



Drain Current : I_D [A]

Drain - Source Voltage : V_{DS} [V]

Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

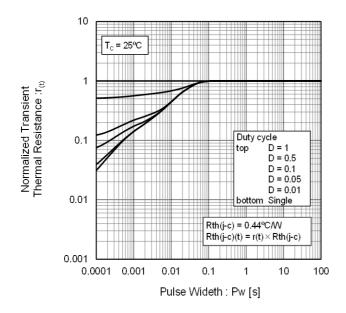
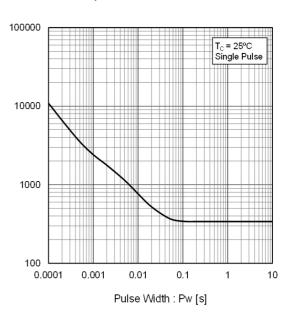


Fig.4 Single Pulse Maximum Power Dissipation



Peak Transient Power: P[W]

Drain Current : I_D [A]

Normalized Breakdown Voltage : $V_{(BR)DSS}$

• Electrical characteristic curves

Fig.5 Typical Output Characteristics(I)

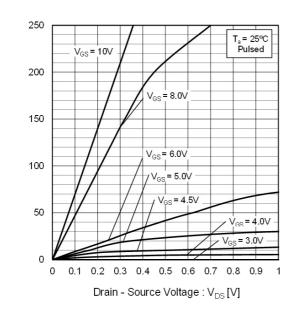
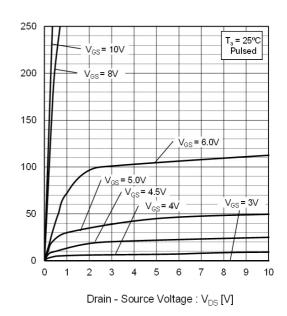


Fig.6 Typical Output Characteristics(II)



Drain Current : I_D [A]

Fig.7 Normalized Breakdown Voltage vs. Junction Temperature

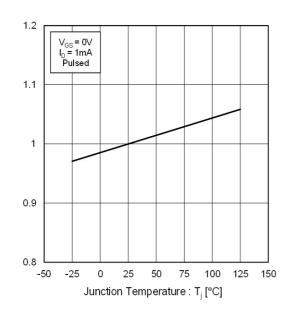
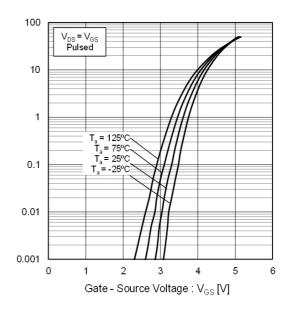


Fig.8 Typical Transfer Characteristics



Drain Current : I_D [A]

Gate Threshold Voltage : VGS(th) [V]

• Electrical characteristic curves

Fig.9 Gate Threshold Voltage vs.
Junction Temperature

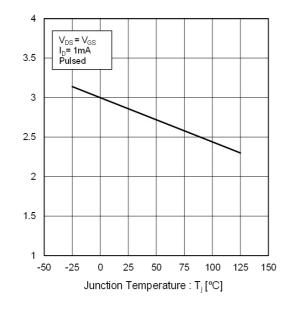


Fig.10 Forward Transfer Admittance vs.
Drain Current

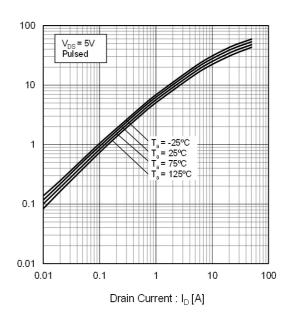


Fig.11 Drain Current Derating Curve

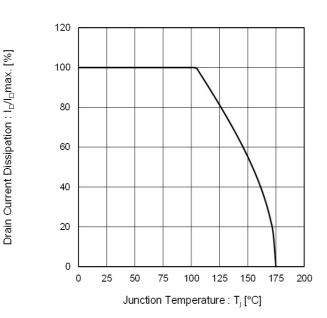
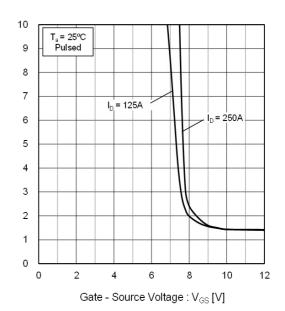


Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage



Static Drain - Source On-State Resistance : $R_{\text{DS}(on)}\left[\text{m}\Omega\right]$

Forward Transfer Admittance : Y_{fs} [S]

• Electrical characteristic curves

Fig.13 Static Drain - Source On - State Resistance vs. Junction Temperature

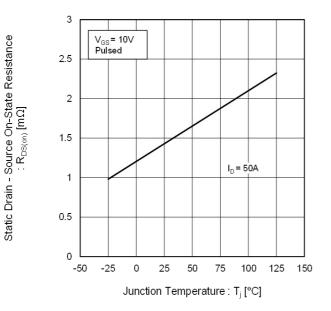
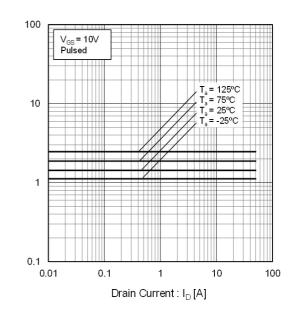


Fig.14 Static Drain - Source On - State Resistance vs. Drain Current



Static Drain - Source On-State Resistance : $R_{DS(\omega)}\left[m\Omega\right]$

Fig.15 Typical Capacitances vs.

Drain - Source Voltage

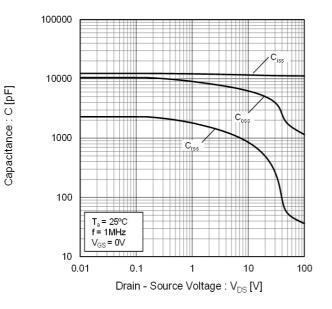
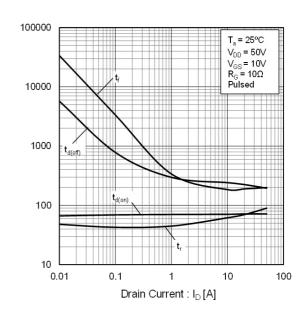


Fig.16 Switching Characteristics



Switching Time : t [ns]

• Electrical characteristic curves

Fig.17 Typical Gate Charge



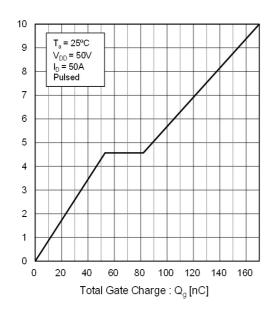
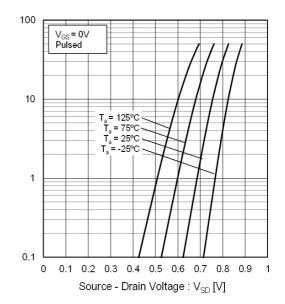


Fig.18 Source Current vs.
Source Drain Voltage



Source Current : Is [A]

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Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

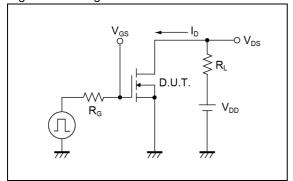


Fig.1-2 Switching Waveforms

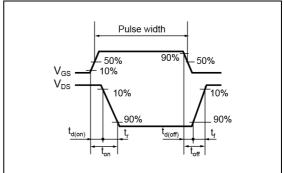


Fig.2-1 Gate Charge Measurement Circuit

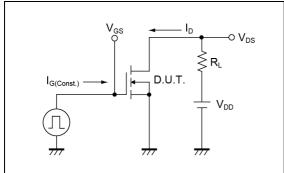


Fig.2-2 Gate Charge Waveform

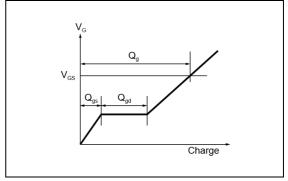


Fig.3-1 Avalanche Measurement Circuit

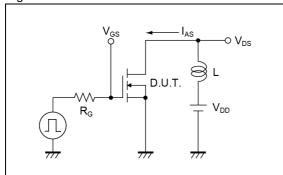
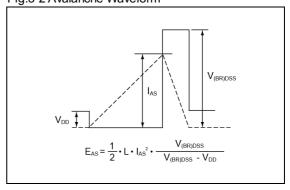


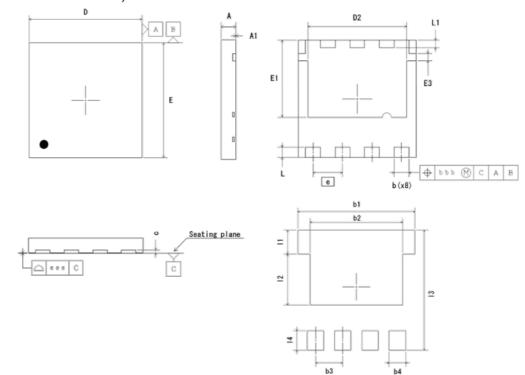
Fig.3-2 Avalanche Waveform



Dimensions

DFN8080-8S

(DFN8080T8LSHAAI)



DIM	Milim	eters	Inc	hes
DIM	Min.	Max.	Min.	Max.
A	0.90	1.10	0.035	0.043
A1	0.00	0.05	0.000	0.002
b	0.90	1.10	0.035	0.043
c	0. 203	3 REF	0.008	B REF
D	7.90	8.10	0.311	0.319
D2	6.60	6.80	0.260	0. 268
E	7.90	8.10	0.311	0.319
E1	5.15	5.35	0.203	0. 211
E3	0.40	0.60	0.016	0.024
е	2.00	2.00 BSC		BSC
L	0.60	0.80	0.024	0. 031
L1	0.40	0.60	0.016	0.024
bbb	0. 10		0.004	
eee	0.	08	0.0	003

Refarenced footprint dimensions

DIM	Milimeters	Inches
MITA	Nom.	Nom.
b1	8. 60	0.339
b2	6. 80	0.268
b3	2. 00	0.079
b4	1. 20	0.047
- 11	1. 76	0.069
12	3. 74	0.147
13	8. 80	0.346
14	1 40	0 055

Dimension in mm/inches



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JÁPAN	USA	EU	CHINA
CLASSⅢ	CL ACCIII	CLASS II b	CL ACCIII
CLASSIV	CLASSⅢ	CLASSⅢ	CLASSⅢ

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 - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

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- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
 may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
 exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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